



60V N-Channel Enhancement Mode MOSFET

Voltage

60 V

Current

48 A

Features

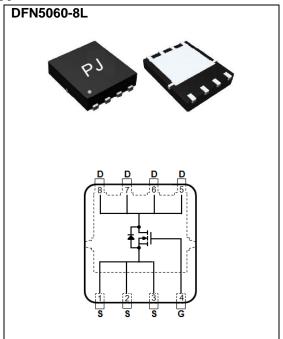
- $R_{DS(ON)}$, $V_{GS}@10V$, $I_D@20A<17m\Omega$
- R_{DS(ON)}, V_{GS}@4.5V, I_D@10A<20mΩ
- High switching speed
- Improved dv/dt capability
- Low reverse transfer capacitance
- AEC-Q101 qualified
- Lead free in compliance with EU RoHS 2.0
- Green molding compound as per IEC 61249 standard

Mechanical Data

• Case: DFN5060-8L Package

• Terminals : Solderable per MIL-STD-750, Method 2026

• Approx. Weight: 0.0028 ounces, 0.08 grams



Maximum Ratings and Thermal Characteristics (T_A=25°C unless otherwise noted)

| PARAMETER | | SYMBOL | LIMIT | UNITS | |
|--|-----------------------|---------------------|-------------|-------|--|
| Drain-Source Voltage | | V _{DS} | 60 | | |
| Gate-Source Voltage | | V_{GS} | <u>+</u> 20 | V | |
| Continuous Drain Current (Note 4) | T _C =25°C | l _D | 48 | A | |
| | T _C =100°C | | 30 | | |
| Pulsed Drain Current (Note 1) | T _C =25°C | I _{DM} | 192 | | |
| Power Dissipation | T _C =25°C | Po | 100 | W | |
| | T _C =100°C | | 50 | | |
| Continuous Drain Current (Note 4) | T _A =25°C | I _D | 7.4 | | |
| | T _A =70°C | | 6.0 | Α | |
| Power Dissipation | T _A =25°C | Po | 2.4 | W | |
| | T _A =70°C | | 1.6 | | |
| Single Pulse Avalanche Energy (Note 6) | | E _{AS} | 45 | mJ | |
| Operating Junction and Storage Temperature Range | | T_{J} , T_{STG} | -55~175 | °C | |
| Typical Thermal Resistance (Note 4,5) | Junction to Case | $R_{	heta JC}$ | 1.5 | °C/W | |
| | Junction to Ambient | $R_{\theta JA}$ | 62.5 | | |

Limited only By Maximum Junction Temperature





Electrical Characteristics (T_A=25 °C unless otherwise noted)

| PARAMETER | SYMBOL | TEST CONDITION | MIN. | TYP. | MAX. | UNITS | |
|----------------------------------|---------------------|---|------|------|--------------|-------|--|
| Static | | | • | | | | |
| Drain-Source Breakdown Voltage | BV _{DSS} | V _{GS} =0V, I _D =250uA | 60 | - | - | V | |
| Gate Threshold Voltage | $V_{GS(th)}$ | $V_{DS}=V_{GS}$, $I_{D}=250uA$ | 1 | 1.7 | 2.5 | V | |
| Drain-Source On-State Resistance | R _{DS(on)} | V _{GS} =10V, I _D =20A | - | 13 | 17 | mΩ | |
| Drain-Source On-State Resistance | R _{DS(on)} | V _{GS} =4.5V, I _D =10A | - | 15 | 20 | | |
| Zero Gate Voltage Drain Current | I _{DSS} | V_{DS} =60V, V_{GS} =0V | - | - | 1 | uA | |
| Gate-Source Leakage Current | I _{GSS} | V _{GS} = <u>+</u> 20V, V _{DS} =0V | - | - | <u>+</u> 100 | nA | |
| Dynamic (Note 7) | | | | | | | |
| Total Gate Charge | Qg | V _{DS} =30V, I _D =10A, V _{GS} =4.5V ^(Note 2,3) | - | 13.5 | - | nC | |
| Gate-Source Charge | Q_gs | | - | 4.8 | - | | |
| Gate-Drain Charge | Q_gd | | - | 4.9 | - | | |
| Input Capacitance | Ciss | V _{DS} =25V, V _{GS} =0V, | - | 1574 | - | pF | |
| Output Capacitance | Coss | | - | 118 | - | | |
| Reverse Transfer Capacitance | Crss | f=1MHZ | - | 77 | - | | |
| Turn-On Delay Time | td _(on) | \/ 45\/ L 4A | - | 11 | - | | |
| Turn-On Rise Time | t _r | V_{DD} =15V, I_{D} =1A, V_{GS} =10V, R_{G} =6 Ω (Note 2,3) | - | 11 | - | ns | |
| Turn-Off Delay Time | td _(off) | | - | 35 | - | | |
| Turn-Off Fall Time | t _f | | - | 8.1 | - | | |
| Drain-Source Diode | | | | | | | |
| Maximum Continuous Drain-Source | _ | | | | 48 | A | |
| Diode Forward Current | I _S | | - | _ | 40 | A | |
| Diode Forward Voltage | V_{SD} | I _S =1A, V _{GS} =0V | - | 0.68 | 1 | V | |

NOTES:

- 1. Pulse width<300us, Duty cycle<2%.
- 2. Essentially independent of operating temperature typical characteristics.
- 3. Repetitive rating, pulse width limited by junction temperature $T_{J(MAX)}$ =150°C. Ratings are based on low frequency and duty cycles to keep initial T_J =25°C.
- 4. The maximum current rating is package limited.
- 5. R_{OJA} is the sum of the junction-to-case and case-to-ambient thermal resistance where the case thermal reference is defined as the solder mounting surface of the drain pins. Mounted on a 1 inch² with 2oz.square pad of copper.
- 6. The test condition is L=0.1mH, I_{AS} =30A, V_{DD} =25V, V_{GS} =10V, Starting T_J =25 $^{\circ}$ C
- 7. Guaranteed by design, not subject to production testing.





TYPICAL CHARACTERISTIC CURVES

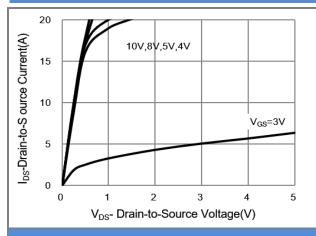


Fig.1 Output Characteristics

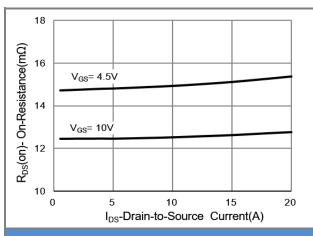
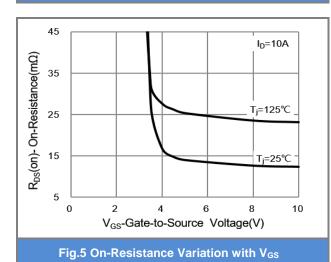


Fig.3 On-Resistance vs. Drain Current



20 V_{DS}=5V V_{DS}=5V

Fig.2 Transfer Characteristics

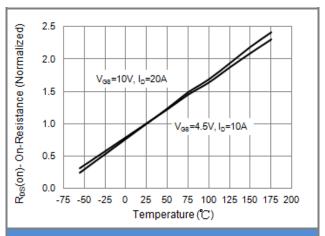


Fig.4 On-Resistance vs. Junction temperature

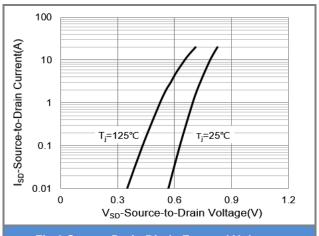


Fig.6 Source-Drain Diode Forward Voltage





TYPICAL CHARACTERISTIC CURVES

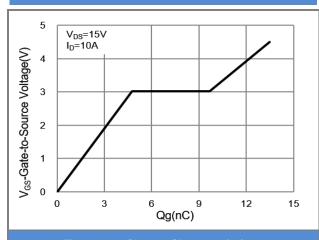


Fig.7 Gate-Charge Characteristics

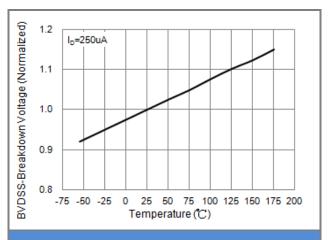


Fig.8 Breakdown Voltage Variation vs. Temperature

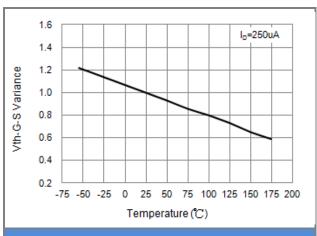


Fig.9 Threshold Voltage Variation with Temperature

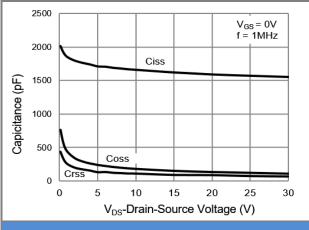
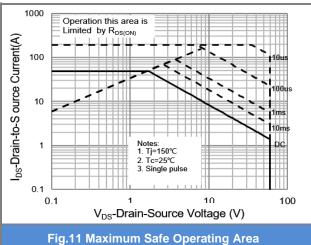


Fig.10 Capacitance vs. Drain-Source Voltage







TYPICAL CHARACTERISTIC CURVES

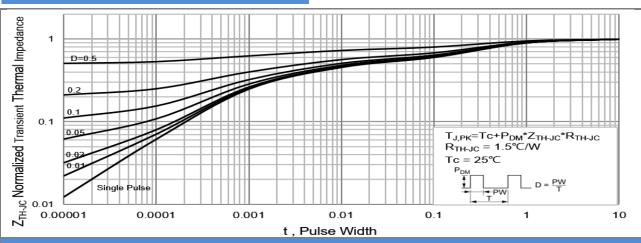


Fig.12 Normalized Transient Thermal Impedance vs. Pulse Width

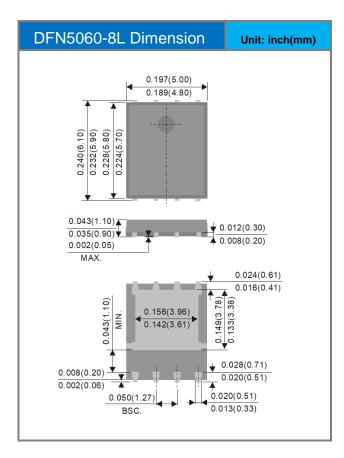


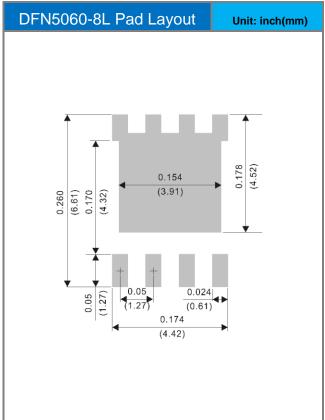


Part No Packing Code Version

| Part No Packing Code | Package Type | Packing Type | Marking | Version | |
|-----------------------|--------------|--------------------|---------|--------------|--|
| PJQ5466A1-AU_R2_000A1 | DFN5060-8L | 3000pcs / 13" reel | Q5466A1 | Halogen free | |

Packaging Information & Mounting Pad Layout









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